



Low-Voltage Dual SPST Analog Switch

FEATURES

- Low Voltage Operation (1.8 V to 5.5 V)
- Low On-Resistance - $r_{DS(on)}$: 1.2 Ω
- Fast Switching - 14 ns
- Low Charge Injection - Q_{INJ} : 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- MSOP-8 Package

BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

APPLICATIONS

- Cellular Phones
- Communication Systems
- Portable Test Equipment
- Battery Operated Systems
- Sample and Hold Circuits

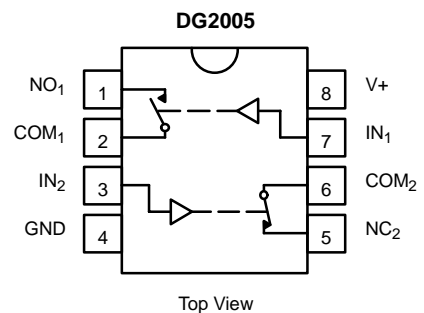
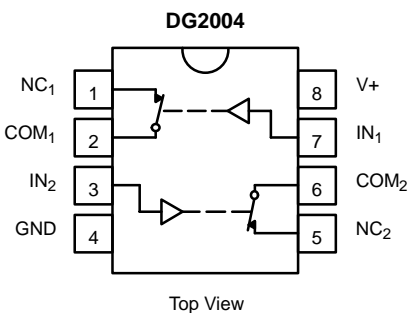
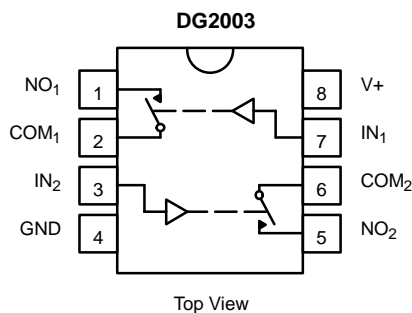
DESCRIPTION

The DG2003/2004/2005 are dual single-pole/single-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, fast switching, low on-resistance ($r_{DS(on)}$: 1.2 Ω) and small physical size (MSOP-8), the DG2003/2004/2005 are ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2003/2004/2005 are built on Vishay Siliconix's low voltage J12 process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE - DG2003 | |
|----------------------|-----|
| Logic | NO |
| 0 | Off |
| 1 | On |

| TRUTH TABLE - DG2004 | |
|----------------------|-----|
| Logic | NC |
| 0 | On |
| 1 | Off |

| TRUTH TABLE - DG2005 | | |
|----------------------|-----------------|-----------------|
| Logic | NO ₁ | NC ₂ |
| 0 | Off | On |
| 1 | On | Off |

| ORDERING INFORMATION | | |
|----------------------|---------|-------------|
| Temp Range | Package | Part Number |
| -40 to 85°C | MSOP-8 | DG2003DQ |
| | | DG2004DQ |
| | | DG2005DQ |

ABSOLUTE MAXIMUM RATINGS

Reference to GND

V+ -0.3 to +6 V

IN, COM, NC, NO^a -0.3 to (V+ + 0.3 V)

Continuous Current (Any terminal) ±50 mA

Peak Current ±200 mA
(Pulsed at 1 ms, 10% duty cycle)

Storage Temperature (D Suffix) -65 to 150°C

Power Dissipation (Packages)^bMSOP-8^c 320 mW

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6.5 mW/°C above 25°C

| SPECIFICATIONS (V+ = 2.0 V) | | | | | | | |
|---|-----------------------|--|---------------------------|-----------------------|------------------|------------------|----------|
| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 2.0 V, ±10%, VIN = 0.4 or 1.6 V ^e | Temp ^a | Limits −40 to 85°C | | | Unit |
| | | | | Min ^b | Typ ^c | Max ^b | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | VNO, VNC, VCOM | | Full | 0 | | V+ | V |
| On-Resistance | rON | V+ = 2.0 V, VCOM = 1.0 V, INO, INC = 1 mA | Room Full ^d | | 7.0 12.5 | 10.0 16.0 | Ω |
| rON Flatness ^d | rON Flatness | V+ = 2.0 V, VCOM = 0 to V+, INO, INC = 1 mA | Room | | 5 | | |
| Switch Off Leakage Current ^f | INO(off), INC(off) | V+ = 2.2 V VNO, VNC = 0.5 V/1.5 V, VCOM = 1.5 V/0.5 V | Room Full ^d | −500 −4.0 | | 500 4.0 | pA nA |
| | ICOM(off) | | Room Full ^d | −500 −4.0 | | 500 4.0 | pA nA |
| Channel-On Leakage Current ^f | ICOM(on) | V+ = 2.2 V, VNO, VNC = VCOM = 0.5 V/1.5 V | Room Full ^d | −500 −4.0 | | 500 4.0 | pA nA |
| Digital Control | | | | | | | |
| Input High Voltage | VINH | | Full | 1.6 | | | V |
| Input Low Voltage | VINL | | Full | | | 0.4 | |
| Input Capacitance ^d | Cin | | Full | | 5 | | pF |
| Input Current | INL or INH | VIN = 0 or V+ | Full | −1 | | 1 | μA |
| Dynamic Characteristics | | | | | | | |
| Turn-On Time | tON | VNO or VNC = 1.5 V, RL = 300 Ω, CL = 35 pF Figures 1 and 2 | Room Full ^d | | 30 | 47 48 | ns |
| Turn-Off Time | tOFF | | Room Full ^d | | 22 | 37 48 | |
| Charge Injection ^d | QINJ | CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, Figure 3 | Room | | 2 | | pC |
| Off-Isolation ^d | OIRR | RL = 50 Ω, CL = 5 pF, f = 1 MHz | Room | | −61 | | dB |
| Crosstalk ^d | XTALK | | Room | | −67 | | |
| NO, NC Off Capacitance ^d | CNO(off), CNC(off) | VIN = 0 or V+, f = 1 MHz | Room | | 53 | | pF |
| Channel-On Capacitance ^d | CON | | Room | | 110 | | |
| Power Supply | | | | | | | |
| Power Supply Range | V+ | | | 1.8 | | 2.2 | V |
| Power Supply Current ^d | I+ | VIN = 0 or V+ | | | 0.02 | 1.0 | μA |
| Power Consumption | PC | | | | | 2.2 | μW |



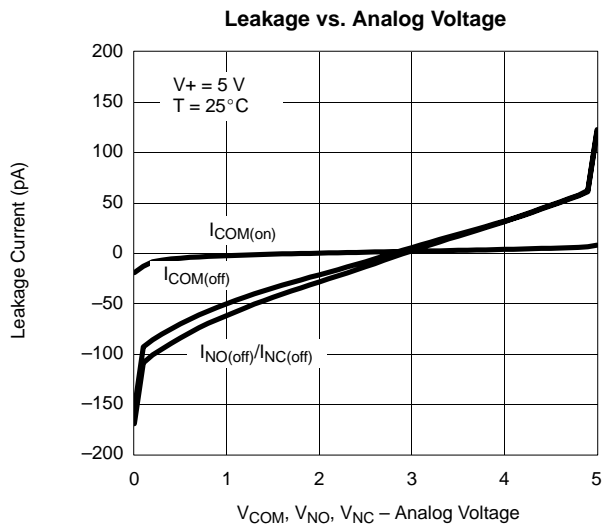
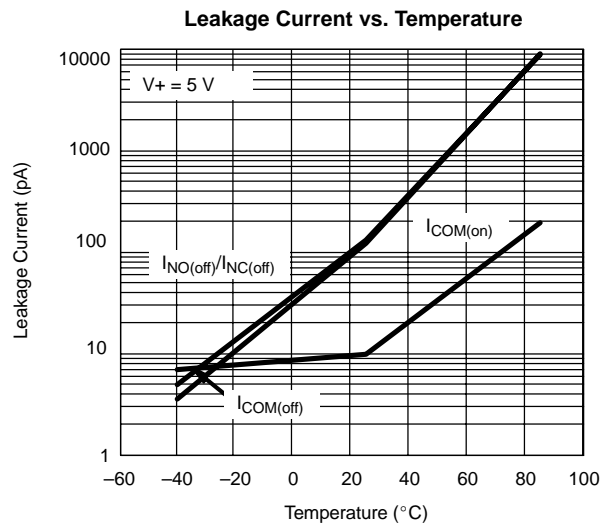
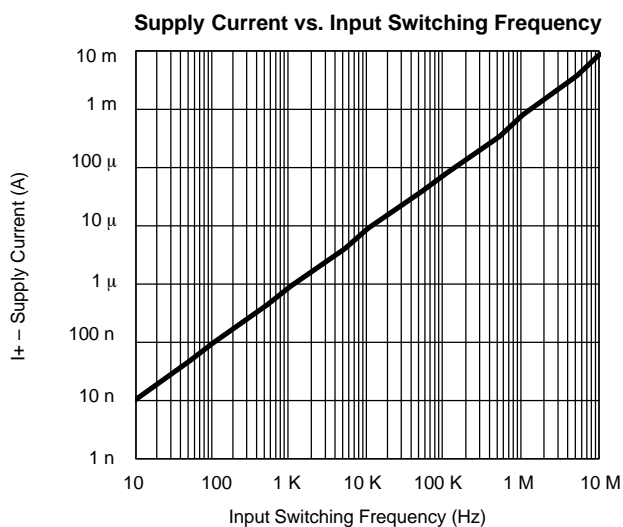
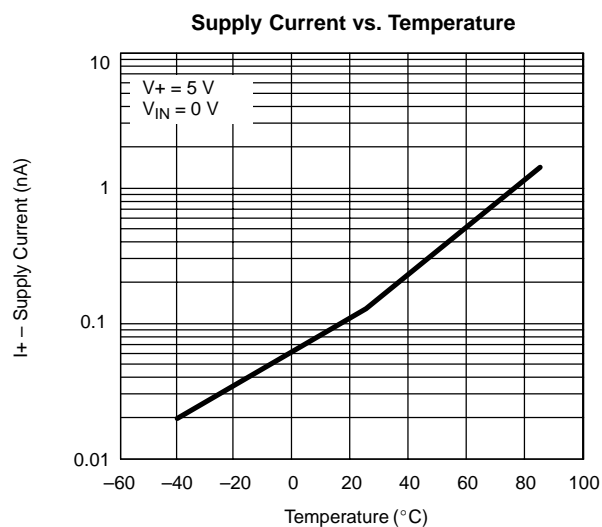
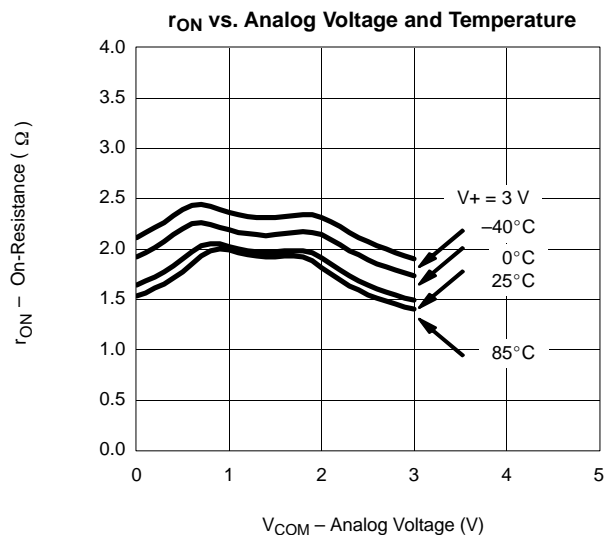
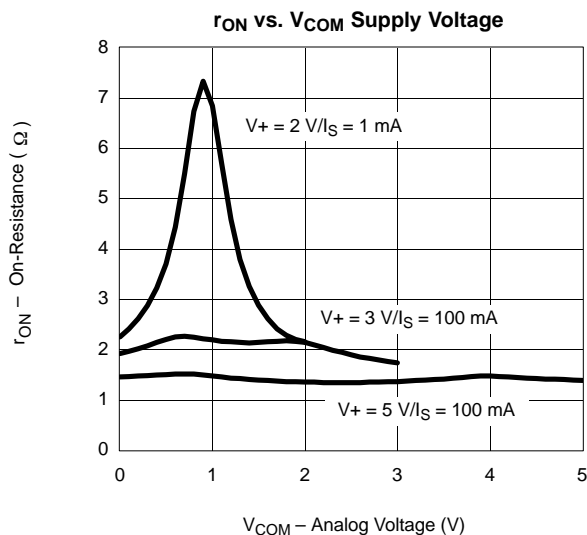
SPECIFICATIONS (V+ = 3.0 V)

| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10%, VIN = 0.4 or 2.0 V ^e | Temp ^a | Limits −40 to 85°C | | | Unit |
|---|-----------------------|---|-------------------|-----------------------|------------------|------------------|----------|
| | | | | Min ^b | Typ ^c | Max ^b | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | VNO, VNC, VCOM | | Full | 0 | | V+ | V |
| On-Resistance | rON | V+ = 2.7 V, VCOM = 1.5 V, INO, INC = 10 mA | Room Full | | 2.2 2.4 | 3.5 3.7 | Ω |
| rON Flatness ^d | rON Flatness | V+ = 2.7 V, VCOM = 0 to V+, INO, INC = 10 mA | Room | | 0.5 | | |
| Switch Off Leakage Current ^f | INO(off), INC(off) | V+ = 3.3 V VNO, VNC = 1 V/3 V, VCOM = 3 V/1 V | Room Full | −500 −6.0 | | 500 6.0 | pA nA |
| | ICOM(off) | | Room Full | −500 −6.0 | | 500 6.0 | pA nA |
| Channel-On Leakage Current ^f | ICOM(on) | V+ = 3.3 V, VNO, VNC = VCOM = 1 V/3 V | Room Full | −500 −6.0 | | 500 6.0 | pA nA |
| Digital Control | | | | | | | |
| Input High Voltage | VINH | | Full | 2 | | | V |
| Input Low Voltage | VINL | | Full | | | 0.4 | |
| Input Capacitance ^d | Cin | | Full | | 5 | | pF |
| Input Current | INIL or IINH | VIN = 0 or V+ | Full | −1 | | 1 | μA |
| Dynamic Characteristics | | | | | | | |
| Turn-On Time ^d | tON | VNO or VNC = 2.0 V, RL = 300 Ω, CL = 35 pF Figure 1 and 2 | Room Full | | 19 | 35 36 | ns |
| Turn-Off Time ^d | tOFF | | Room Full | | 17 | 31 34 | |
| Charge Injection ^d | QINJ | CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, Figure 3 | Room | | 1 | | pC |
| Off-Isolation ^d | OIRR | RL = 50 Ω, CL = 5 pF, f = 1 MHz | Room | | −61 | | dB |
| Crosstalk ^d | XTALK | | Room | | −67 | | |
| NO, NC Off Capacitance ^d | CNO(off), CNC(off) | VIN = 0 or V+, f = 1 MHz | Room | | 53 | | pF |
| Channel-On Capacitance ^d | CON | | Room | | 110 | | |
| Power Supply | | | | | | | |
| Power Supply Range | V+ | | | 2.7 | | 3.3 | V |
| Power Supply Current | I+ | VIN = 0 or V+ | | | 0.02 | 1.0 | μA |
| Power Consumption | PC | | | | | 3.3 | μW |

| SPECIFICATIONS (V+ = 5.0 V) | | | | | | | |
|-------------------------------------|-----------------------|---|-------------------|-----------------------|------------------|------------------|------|
| Parameter | Symbol | Test Conditions Otherwise Unless Specified V+ = 5 V, ± 10%, VIN = 0.8 or 2.4 V ^e | Temp ^a | Limits –40 to 85°C | | | Unit |
| | | | | Min ^b | Typ ^c | Max ^b | |
| Analog Switch | | | | | | | |
| Analog Signal Range ^d | VNO, VNC, VCOM | | Full | 0 | | V+ | V |
| On-Resistance | rON | V+ = 4.5 V, VCOM = 3 V, INO, INC = 10 mA | Room Full | | 1.2 1.6 | 2.5 2.7 | Ω |
| rON Flatness ^d | rON Flatness | V+ = 4.5 V, VCOM = 0 to V+, INO, INC = 10 mA | Room | | 0.2 | | |
| Switch Off Leakage Current | INO(off), INC(off) | V+ = 5.5 V VNO, VNC = 1 V/4.5 V, VCOM = 4.5 V/1 V | Room Full | –1.0 –8.0 | | 1.0 8.0 | nA |
| | ICOM(off) | | Room Full | –1.0 –8.0 | | 1.0 8.0 | |
| Channel-On Leakage Current | ICOM(on) | V+ = 5.5 V, V+ = 5.5 V VNO, VNC = VCOM = 1 V/4.5 V | Room Full | –1.0 –8.0 | | 1.0 8.0 | |
| Digital Control | | | | | | | |
| Input High Voltage | VINH | | Full | 2.4 | | | V |
| Input Low Voltage | VINL | | Full | | | 0.8 | |
| Input Capacitance | Cin | | Full | | 5 | | pF |
| Input Current | IINL or IINH | VIN = 0 or V+ | Full | –1 | | 1 | μA |
| Dynamic Characteristics | | | | | | | |
| Turn-On Time ^d | tON | VNO or VNC = 3 V, RL = 300 Ω, CL = 35 pF Figure 1 and 2 | Room Full | | 13 | 28 31 | ns |
| Turn-Off Time ^d | tOFF | | Room Full | | 19 | 22 31 | |
| Charge Injection ^d | QINJ | CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, Figure 3 | Room | | 1 | | pC |
| Off-Isolation ^d | OIRR | RL = 50 Ω, CL = 5 pF, f = 1 MHz | Room | | –61 | | dB |
| Crosstalk ^d | XTALK | | Room | | –67 | | |
| Source-Off Capacitance ^d | CNO(off), CNC(off) | VIN = 0 or V+, f = 1 MHz | Room | | 51 | | pF |
| Channel-On Capacitance ^d | CON | | Room | | 110 | | |
| Power Supply | | | | | | | |
| Power Supply Range | V+ | | | 4.5 | | 5.5 | V |
| Power Supply Current | I+ | VIN = 0 or V+ | | | 0.02 | 1.0 | μA |
| Power Consumption | PC | | | | | 5.5 | μW |

Notes:

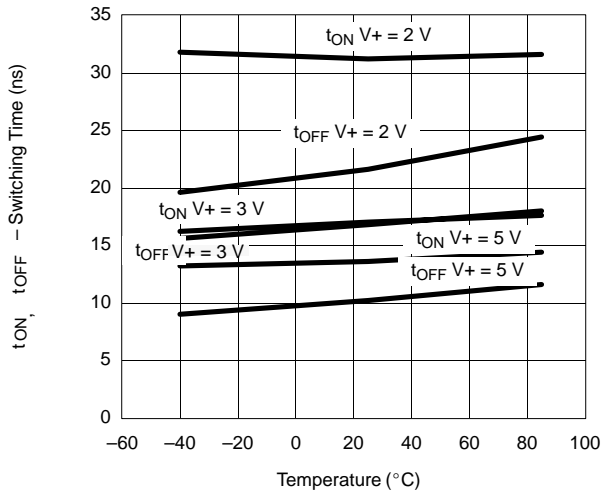
- Room = 25°C, Full = as determined by the operating suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for design aid only, not guaranteed nor subject to production testing.
- Guarantee by design, nor subjected to production test.
- V_{IN} = input voltage to perform proper function.
- Guaranteed by 5-V leakage testing, not production tested.

**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**

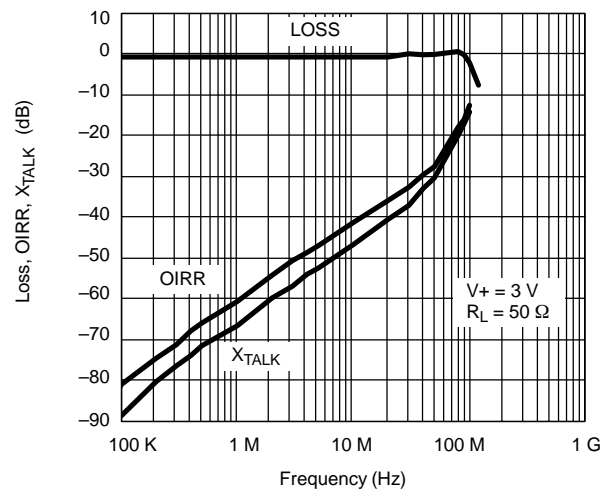


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

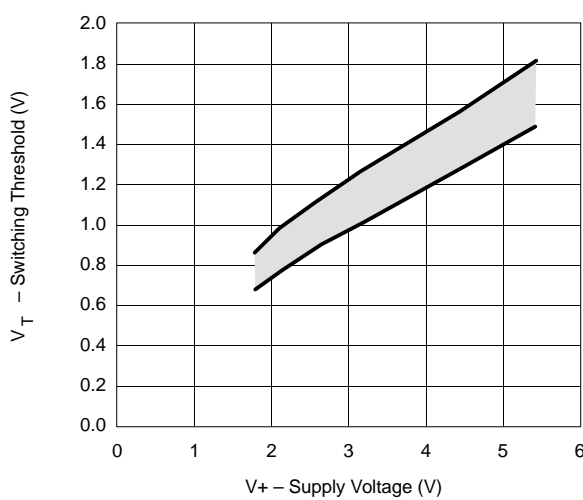
Switching Time vs. Temperature and Supply Voltage



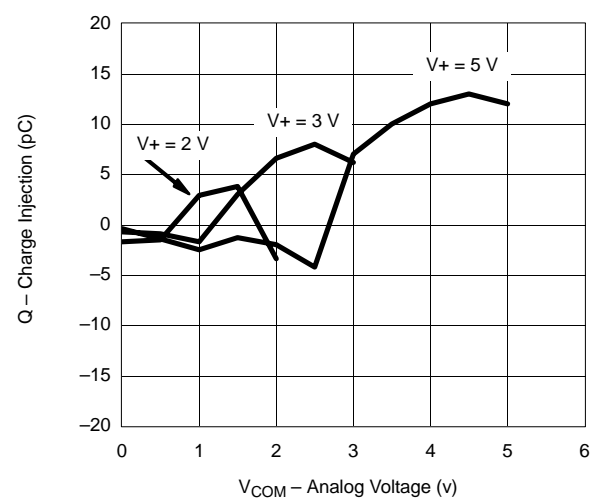
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



Switching Threshold vs. Supply Voltage



Charge Injection vs. Analog Voltage



TEST CIRCUITS

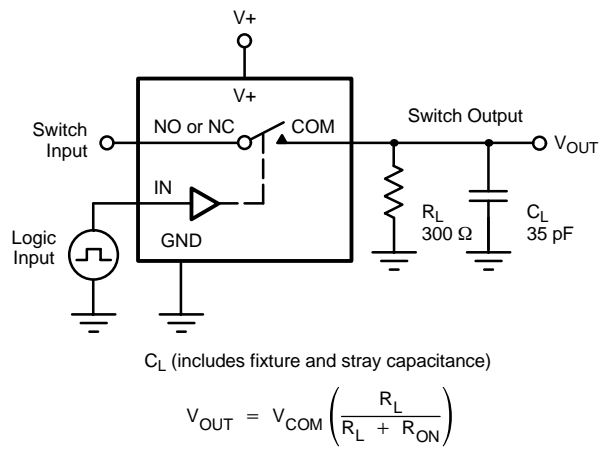
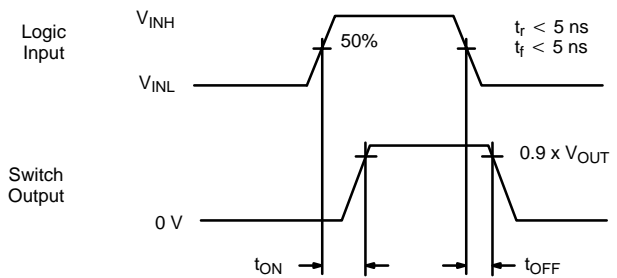
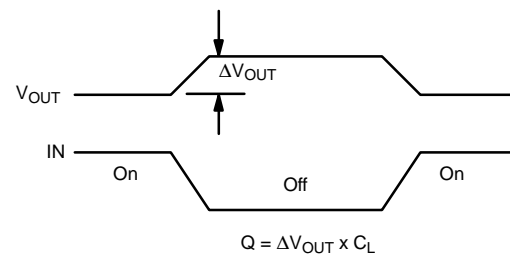
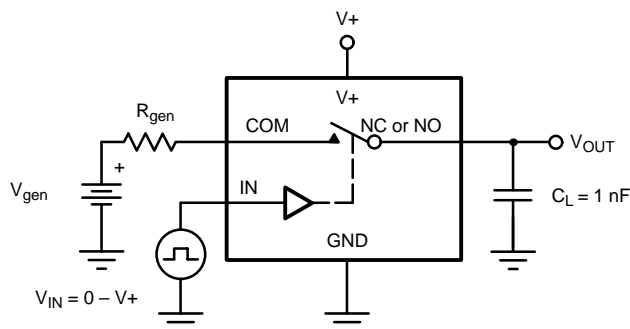


FIGURE 1. Switching Time



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.



IN depends on switch configuration: input polarity determined by sense of switch.

FIGURE 2. Charge Injection

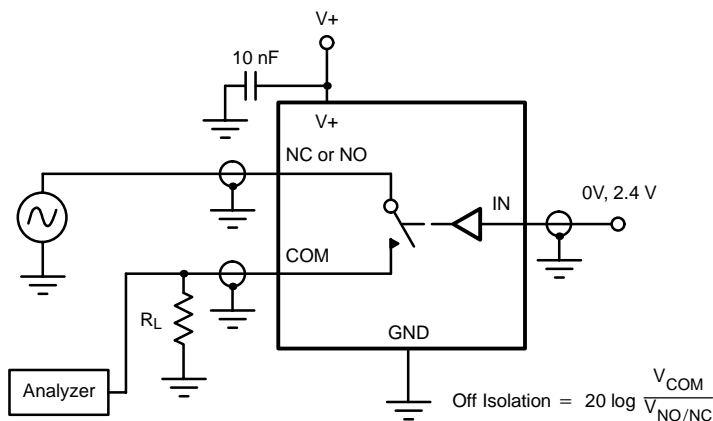


FIGURE 3. Off-Isolation

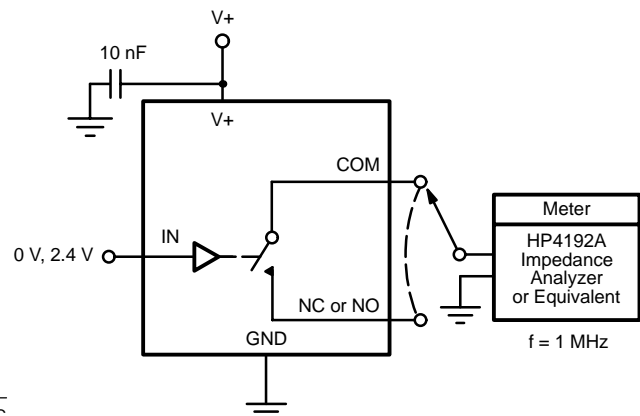


FIGURE 4. Channel Off/On Capacitance